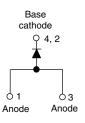


Vishay Semiconductors

Schottky Rectifier, 3.0 A





D-PAK (TO-252AA
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PRODUCT SUMMARY							
Package	D-PAK (TO-252AA)						
I _{F(AV)}	3.0 A						
V _R	20 V, 30 V, 40 V						
V_F at I_F	0.49 V						
I _{RM}	20 mA at 125 °C						
T _J max.	150 °C						
Diode variation	Single die						
E _{AS}	8 mJ						

FEATURES

- Popular D-PAK outline
- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 $^\circ\text{C}$

DESCRIPTION

The VS-MBRD320PbF, VS-MBRD330PbF, VS-MBRD340PbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS										
SYMBOL	CHARACTERISTICS	VALUES	UNITS							
I _{F(AV)}	Rectangular waveform	3.0	А							
V _{RRM}		20 to 40	V							
I _{FSM}	t _p = 5 μs sine	490	А							
V _F	3 Apk, T _J = 125 °C	0.49	V							
TJ		- 40 to 150	۵°							

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-MBRD320PbF	VS-MBRD330PbF	VS-MBRD340PbF	UNITS			
Maximum DC reverse voltage	V _R	20	30	40	V			
Maximum working peak reverse voltage	V _{RWM}	20	50	40	v			

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS				
Maximum average forward current	I _{F(AV)}	50 % duty cycle at T_L = 133 °C, re	50 % duty cycle at T_L = 133 °C, rectangular waveform						
Maximum peak one cycle non-repetitive surge current	1	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	490	А				
	IFSM	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	75					
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1 A, L = 16 mH		8.0	mJ				
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μs Frequency limited by T_J maximum V_A = 1.5 x V_R typical		1.0	А				



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ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CO	NDITIONS	TYP.	MAX.	UNITS			
Maximum forward voltage drop See fig. 1		3 A	T.I = 25 °C	0.48	0.6	v			
	V _{FM} ⁽¹⁾	6 A	1j=25 C	0.58	0.7				
		3 A	T.I = 125 °C	0.41	0.49				
		6 A	1j = 125 C	0.55	0.625				
Maximum reverse leakage current	I _{RM} ⁽¹⁾	$T_J = 25 \ ^\circ C$	$V_{\rm B} = Rated V_{\rm B}$	0.02	0.2	mA			
See fig. 2		T _J = 125 °C	$v_{\rm R} = naleu v_{\rm R}$	10.7	20				
Typical junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal ran	189	-	pF				
Typical series inductance	L _S	Measured lead to lead 5 m	5.0	-	nH				
Maximum voltage rate of change	dV/dt	Rated V _R	-	10 000	V/µs				

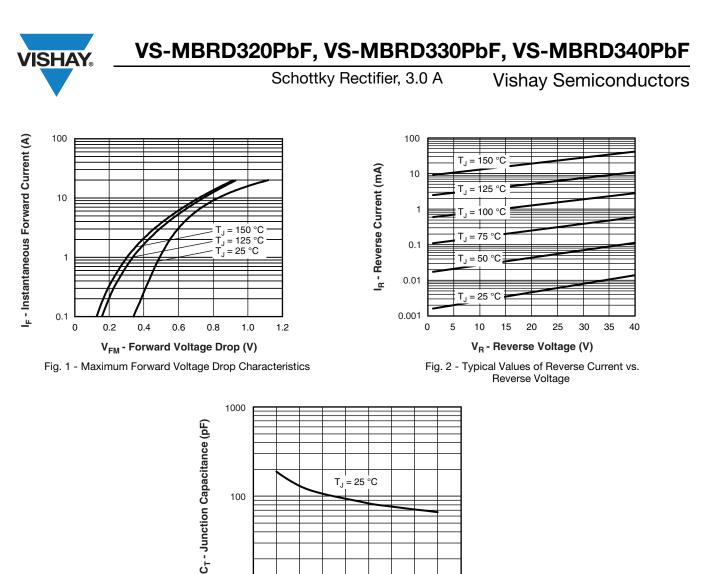
Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Maximum junction temperature range	T _J ⁽¹⁾		- 40 to 150	°C					
Maximum storage temperature range	T _{Stg}		- 40 to 175	C					
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	6.0	°C 444					
Maximum thermal resistance, junction to ambient	R _{thJA}		80	°C/W					
Approvimate weight			0.3	g					
Approximate weight			0.01	oz.					
			MBRD320						
Marking device		Case style D-PAK (similar to TO-252AA)	MBRD330						
			MBRD340						

Note

(1) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink



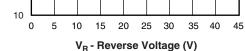


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

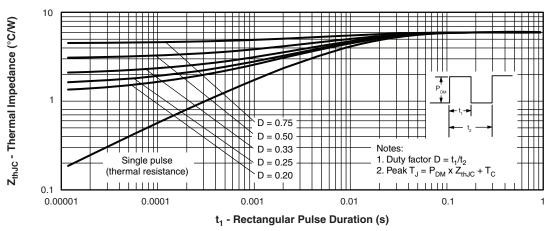
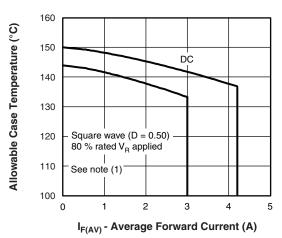
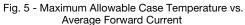


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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Schottky Rectifier, 3.0 A





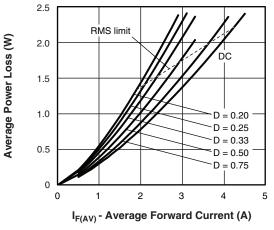
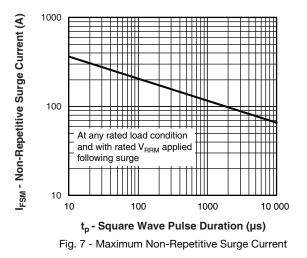


Fig. 6 - Forward Power Loss Characteristics



Note

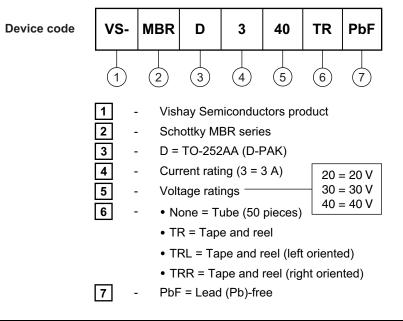
- (1)
- Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$; Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6); Pd_{REV} = Inverse power loss = $V_{R1} \times I_R$ (1 D); I_R at V_{R1} = 80 % rated V_R



Schottky Rectifier, 3.0 A

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ORDERING INFORMATION TABLE



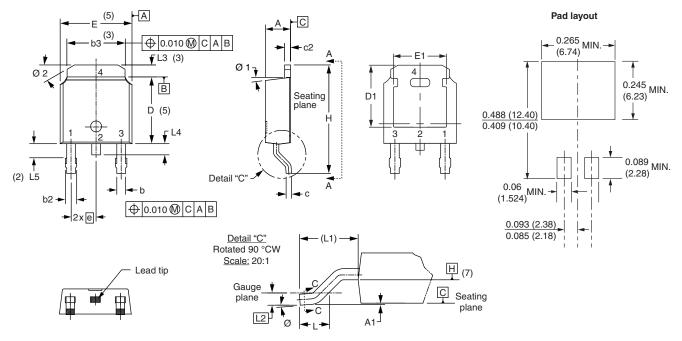
LINKS TO RELATED DOCUMENTS							
Dimensions www.vishay.com/doc?95016							
Part marking information	www.vishay.com/doc?95059						
Packaging information	www.vishay.com/doc?95033						



Vishay Semiconductors

D-PAK (TO-252AA)

DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	MILLIMETERS		INCHES		SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES	STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	2.18	2.39	0.086	0.094		е	2.29	BSC	0.090	BSC	
A1	-	0.13	-	0.005		Н	9.40	10.41	0.370	0.410	
b	0.64	0.89	0.025	0.035		L	1.40	1.78	0.055	0.070	
b2	0.76	1.14	0.030	0.045		L1	2.74	BSC	0.108	REF.	
b3	4.95	5.46	0.195	0.215	3	L2	0.51	BSC	0.020	BSC	
с	0.46	0.61	0.018	0.024		L3	0.89	1.27	0.035	0.050	3
c2	0.46	0.89	0.018	0.035		L4	-	1.02	-	0.040	
D	5.97	6.22	0.235	0.245	5	L5	1.14	1.52	0.045	0.060	2
D1	5.21	-	0.205	-	3	Ø	0°	10°	0°	10°	
E	6.35	6.73	0.250	0.265	5	Ø1	0°	15°	0°	15°	
E1	4.32	-	0.170	-	3	Ø2	25°	35°	25°	35°	

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension uncontrolled in L5

⁽³⁾ Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

⁽⁴⁾ Section C - C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip

(5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁶⁾ Dimension b1 and c1 applied to base metal only

⁽⁷⁾ Datum A and B to be determined at datum plane H

⁽⁸⁾ Outline conforms to JEDEC outline TO-252AA

Document Number: 95016



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